

Low-energy instability of flexural phonons in graphene

P. San-Jose^a, J. González^a and F. Guinea^b

^a*Instituto de Estructura de la Materia, Consejo Superior de Investigaciones Científicas, Serrano 123, 28006 Madrid, Spain*

^b*Instituto de Ciencia de Materiales de Madrid, Consejo Superior de Investigaciones Científicas, Cantoblanco, Madrid, Spain*
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We study the effect exerted by the electrons on the flexural phonons in graphene, accounting for the attractive interaction created by the exchange of electron-hole excitations. Combining the self-consistent computation of the phonon self-energy with renormalization group methods, we show that graphene has two different phases corresponding to soft and strong renormalization of the bending rigidity in the long-wavelength limit. In the first case, the system may have an intermediate scale in which the phonon dispersion is softened, but it manages finally to become increasingly rigid over large distance scales. The strongly renormalized phase is closer however to critical behavior, with an effective rigidity that becomes pinned in practice at very small values, implying a very large susceptibility for the development of a condensate of the flexural phonon field.

In recent years, the feasibility of fabricating graphene layers a single atom thick[1–3] has led to a great deal of activity, because of their novel electronic properties and potential applications[4]. Beyond its remarkable electronic transport attributes, it is becoming increasingly clear that graphene’s mechanical and electromechanical properties are just as remarkable. Despite its extreme thinness, it behaves as a stable metallic membrane with finite elastic moduli and rigidity. From this point of view, one of the most intriguing features of graphene is its tendency to develop ripples with a characteristic length scale. In exfoliated graphene, these ripples are correlated to some extent with the irregularities of the substrate on which the graphene sheet is deposited. But there is also evidence that they arise in part as an effect intrinsic to the two-dimensional membrane. When graphene was first fabricated, it came as a surprise that a purely two-dimensional material could exist, without being destabilized by large thermal or quantum fluctuations. From a theoretical point of view, it has been shown however that the coupling of flexural phonons to the in-plane vibrations in a crystalline membrane provides a mechanism to stabilize the two-dimensional system, leading to a finite critical temperature for the crumpling transition[7]. The ripples are usually viewed then as a sort of imprint of the large fluctuations that should be present in the low-dimensional material[8].

The ripples are expected to have a significant impact on the electronic transport in graphene[9]. More generally, it has been shown that the scattering with flexural phonons may lead to a reduction of the lifetime of electron quasiparticles in graphene[10]. On the other hand, the effect exerted by the electrons on the out-of-plane vibrations of a metallic membrane has been much less studied. There have been partial approaches in which the coupling of the charge density to the flexural phonons has been considered[11–13], but a zero temperature scaling analysis characterizing the possible critical behavior in the system has not been undertaken until now.

In this paper we investigate the many-body effects on flexural phonons in graphene, in a theory where these are coupled to the electron charge density as well as to the

in-plane vibrations. These are known to give rise to a repulsive self-interaction between flexural phonons. We show that the exchange of electron-hole excitations leads to an interaction with the opposite character, although it plays in general the role of an irrelevant perturbation in the system. We will analyze the conditions in which this attraction may have a significant effect, finding that it leads in that case to a softening of the acoustic branch of out-of-plane phonons in graphene. The effective bending rigidity can be then strongly suppressed beyond a certain length scale, making the system very susceptible to the development of a condensate (nonvanishing average value) for the out-of-plane phonon field.

We characterize the shape of the graphene sheet by the vector field $\mathbf{u} = (u_1, u_2, h)$, where u_1, u_2 represent the in-plane displacement with respect to the equilibrium position and h is the out-of-plane shift. The deformation of the membrane is analyzed in terms of the strain tensor u_{ij} , given by

$$u_{ij} = \frac{1}{2}(\partial_i u_j + \partial_j u_i + \partial_i h \partial_j h) \quad (1)$$

Thus, the action of the system has a term governing the dispersion of flexural phonons and depending on the mass density ρ and the rigidity κ

$$S_{\text{free}} = \frac{1}{2} \int dt d^2x (\rho (\partial_t h)^2 - \kappa (\nabla^2 h)^2) \quad (2)$$

while the dynamics of the in-plane phonons is controlled by a term of the form

$$S_u = \frac{1}{2} \int dt d^2x (\rho (\partial_t u_i)^2 - 2\mu \text{Tr} u_{ij}^2 - \lambda (\text{Tr} u_{ij})^2) \quad (3)$$

where μ and λ are the Lamé coefficients.

The term S_u contains a quartic self-interaction for the out-of-plane phonon field h . It is well-known that this interaction has to be taken into account for the description of stable crystalline membranes, as the soft dispersion in (2) leads to infrared divergences that cannot be tamed in the free theory[7]. The novel effect arising in graphene is that the electronic charge couples to the displacement

of the sheet, in such a way that it gives rise to another source of self-interaction between the phonon fields. We will consider the effect of electrons from the π bands of graphene, represented by the field $\Psi(x)$. Accounting for the fact that the coupling must take place through the trace of the strain tensor u_{ij} , we add to the action a new term

$$S_{\text{e-ph}} = -g \int dt d^2x \Psi^\dagger(x) \Psi(x) \text{Tr} u_{ij} \quad (4)$$

The electron-phonon coupling g has dimensions of energy and is directly related to the deformation potential of the graphene lattice, which has a microscopic origin.

Assuming that the electron correlations are weak in graphene, we may represent the dynamics of the $\Psi(x)$ field by a quadratic hamiltonian, matching at low energies the usual expression for the Dirac fermion fields. The electron degrees of freedom can be integrated out at this point, leading from (4) to a new phonon contribution to the action, to be added to (2) and (3),

$$S_{\text{u}'} = -\frac{1}{2}g^2 \int d\omega_q d^2q \chi(\mathbf{q}, \omega_q) (\text{Tr} u_{ij}) (\text{Tr} u_{ij}) \quad (5)$$

where $\chi(\mathbf{q}, \omega_q)$ is the density-density correlator depending on frequency and momentum variables. Terms that are higher order in $\text{Tr} u_{ij}$ can be generated after integration of the electron fields, but they turn out to be more irrelevant perturbations in the approach developed in what follows.

Since the energy scale of electronic excitations (for a given momentum) are much larger than the phonon energies, we can safely take the limit $\omega = 0$ in the charge susceptibility. In the Dirac theory, we have in particular $\chi(\mathbf{q}, 0) = -|\mathbf{q}|/v_F$. We observe that the new contribution (5) tends to cancel the term with the Lamé coefficient λ in (3). After following the usual procedure to integrate the in-plane phonons u_i [7], we get the total action for the flexural phonons

$$S = \frac{1}{2} \int d\omega_q d^2q (\rho \omega_q^2 h^2 - \kappa \mathbf{q}^4 h^2) - \frac{1}{2} \int d\omega_q d^2q K(q) \tilde{u}_{ij}(\mathbf{q}, \omega_q) \tilde{u}_{ij}(-\mathbf{q}, -\omega_q) \quad (6)$$

where $\tilde{u}_{ij}(\mathbf{q}, \omega_q)$ is the Fourier transform of $(1/2)P_{ij}\partial_i h \partial_j h$, P_{ij} being the transverse projector, and the quartic coupling is (in the Dirac theory)

$$K(q) = \frac{4\mu(\mu + \lambda - g^2|\mathbf{q}|/v_F)}{2\mu + \lambda - g^2|\mathbf{q}|/v_F} \quad (7)$$

Negative values of the coupling function $K(q)$ may lead to an instability of the graphene sheet, as they represent an attractive interaction between the flexural phonons. The phonon self-energy and the interaction vertices are actually affected by logarithmic divergences in the energy cutoff, which makes it necessary to keep track of the low-energy dependence of the couplings. In order to study

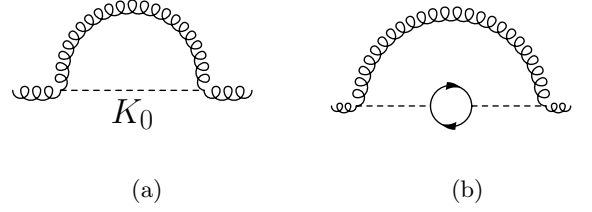


FIG. 1. First order corrections to the self-energy of flexural phonons (represented by a wiggly line) arising from (a) the four-phonon interaction K_0 and (b) the exchange of electron-hole excitations (represented by the bubble with arrow lines).

the competition between positive and negative couplings in (7), we may approximate this coupling function by the constant term $K_0 = 4\mu(\mu + \lambda)/(2\mu + \lambda)$ and the dominant powers of $|\mathbf{q}|$

$$K(q) \approx K_0 - G_1 |\mathbf{q}| - G_2 \mathbf{q}^2 \quad (8)$$

Neglecting higher-order terms in $|\mathbf{q}|$ amounts to disregarding the exchange of an increasing number of electron-hole pairs in the in-plane phonon propagator, which is justified as long as the pole arising from the denominator of (7) is not included within the first Brillouin zone of a real graphene system. This is consistent with an estimate for the on-site deformation potential for the in-plane phonons $g_{\text{in}} \approx 8$ eV [14], that is the coupling appearing in the denominator of Eq. (7).

The different interactions tend to modify the low-energy behavior of the rigidity κ in opposite directions depending on their attractive or repulsive character. This can be seen through the corrections to the phonon self-energy $\Sigma(\mathbf{p}, \omega_p)$ represented in Fig. 1. Computing the full propagator of the flexural phonons from the expression $D^{-1}(\mathbf{p}, \omega_p) = \omega_p^2 - (\kappa_0/\rho)\mathbf{p}^4 - \Sigma(\mathbf{p}, \omega_p)$, we find the renormalized bending rigidity $\kappa(\mathbf{p})$ given by the equation

$$\frac{\kappa(\mathbf{p})}{\rho} = \frac{\kappa_0}{\rho} + \frac{1}{8\pi^2} \int_0^{q_c} dq \int_0^{2\pi} d\phi \sin^4(\phi) \frac{K_0 - G_1|\mathbf{p} - \mathbf{q}| - G_2|\mathbf{p} - \mathbf{q}|^2}{\rho^2|\mathbf{p} - \mathbf{q}|^4} \frac{|\mathbf{q}|^3}{\sqrt{\kappa(\mathbf{r})/\rho}} \quad (9)$$

A self-consistent treatment of the many-body theory requires that the rigidity arising in the integrand of (10) from the phonon propagator must be also taken as $\kappa(\mathbf{p})$. This leads to an integral equation, that can be solved to obtain the effective momentum dependence of the renormalized parameter.

We have represented in Fig. 2(a) the result of solving Eq. (10) in different regimes of the coupling g . We observe that, for a sufficiently large value g_c , the function $\kappa(\mathbf{p})$ vanishes at a certain momentum, bouncing back for smaller values of $|\mathbf{p}|$. In this picture, g_c plays the role of critical coupling, as larger values of g would actually lead to negative values of the bending rigidity, implying the absence of a self-consistent solution. In that case, however, a more refined analysis has to be applied in order

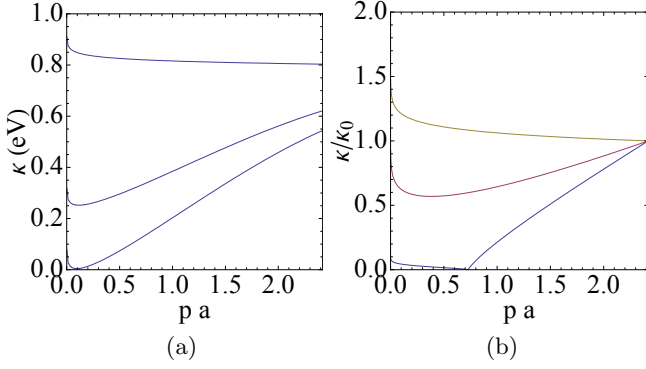


FIG. 2. (a) Effective momentum dependence of the bending rigidity obtained from the solution of Eq. (10) for values of G_1 and G_2 corresponding (from top to bottom) to a deformation potential g of flexural phonons equal to 0, 24 and 26.3 eV. (b) Scaling of κ in the renormalization group approach, for bare values of the deformation potential equal (from top to bottom) to 0, 22 and 29 eV. In both approaches, we have taken the bare value of $a^2 K_0$ equal to 18 eV.

to capture the low-energy scaling of the couplings K_0 , G_1 and G_2 , which becomes quite significant when the effective bending rigidity gets very small.

We apply then a Wilsonian renormalization group method starting from a high-energy cutoff $E_c = \sqrt{\kappa_0/\rho} q_c^2$ for some large momentum q_c , and performing a progressive integration of energy shells to approach the low-energy regime. The bare coupling K_0 is corrected to lowest order by the one-loop diagram made of the exchange of two flexural phonons, which shows a logarithmic dependence on the cutoff q_c . This can be absorbed into a suitable renormalization of the effective coupling. Under a differential change of the energy scale, we find the scaling with the running cutoff $q \rightarrow 0$

$$q \frac{\partial(K_0/\rho^2)}{\partial q} = \frac{3}{64\pi} \frac{(K_0/\rho^2)^2}{(\kappa/\rho)^{3/2}} \quad (10)$$

The couplings G_1 and G_2 correspond to effective phonon interactions mediated by the exchange of electron-hole excitations, and they also undergo a logarithmic renormalization from the exchange of flexural phonons. However, the main source of scaling for these couplings arises at the classical level, as the respective terms in the effective action pick up anomalous factors $1/\sqrt{s}$ and $1/s$ when shrinking the energy scale from E_c to E_c/s . We find then the respective anomalous dimensions $\Delta = -1/2$ and -1 , which lead to the scaling equations for $n = 1, 2$

$$q \frac{\partial G_n}{\partial q} = n G_n + \frac{3}{32\pi} \frac{(K_0/\rho^2) G_n}{(\kappa/\rho)^{3/2}} \quad (11)$$

The main scaling dependence is given by the behavior

$$G_n(q) = q^n \tilde{G}_n(q) \quad (12)$$

where the couplings $\tilde{G}_n$ are subject to a purely logarithmic scaling in the same fashion as K_0 .

A scaling equation can be also written for the rigidity κ , as the self-energy diagrams in Fig. 1 actually display a logarithmic dependence on the cutoff q_c . Taking into account the irrelevant character of the couplings G_n , we find that under a variation of the momentum scale q

$$q \frac{\partial \kappa/\rho}{\partial q} = -\frac{3}{16\pi} \frac{K_0/\rho^2}{(\kappa/\rho)^{1/2}} + \frac{3}{16\pi} \sum_n q^n \frac{\tilde{G}_n/\rho^2}{(\kappa/\rho)^{1/2}} \quad (13)$$

Eq. (13) has to be solved then together with (10) and (11) in order to obtain the behavior of the effective rigidity κ . We note that, in real graphene samples, the bare values of the couplings K_0 and G_n place in general the system in the weak-coupling regime. On the one hand, the energy scale of K_0 is given by $a^2 4\mu(\mu + \lambda)/(2\mu + \lambda) \approx 20$ eV [15], where $a = 1.4$ Å is the interatomic spacing. The coupling from the electronic sector is subject to the uncertainty in the estimates of the deformation potential for out-of-plane vibrations, leading to a wide range of values with $g \sim 20 - 30$ eV [16]. On the other hand, we have the energy scale $a^2 \rho^2 (\kappa/\rho)^{3/2}$, which has a nominal value of ≈ 40 eV in graphene. When κ/ρ becomes very small, however, the rate of decrease of K_0 , $\tilde{G}_1$ and $\tilde{G}_2$ is greatly increased, leading to significant differences with respect to the behavior of the effective rigidity obtained from the self-consistent equation (10).

The behavior of κ obtained from the scaling equations is shown in Fig. 2(b) for different bare values of g . For small values of this coupling, we see that the effective rigidity has a steadily increasing trend as $q \rightarrow 0$. There is however a regime of large g , corresponding to values of the deformation potential $g \sim 25 - 30$ eV, in which κ is significantly reduced due to the electron-phonon interaction. At some point, κ may be even suppressed by several orders of magnitude, but without vanishing as in the self-consistent approach shown above. Here we find instead that κ always bounces back from zero, though it may become trapped in a range of very small values as the effective couplings K_0 , G_1 and G_2 are themselves quickly renormalized very close to zero.

We find therefore that graphene has two different phases corresponding to soft and strong renormalization of κ as $q \rightarrow 0$. In the first case, the system may have an intermediate scale in which the effective κ is reduced, but it manages finally to become increasingly rigid over large distance scales. In the strongly renormalized phase, however, the effective rigidity becomes pinned in practice at very small values below a certain momentum scale.

Although the self-consistent solutions of Eq. (10) miss the renormalization of the couplings at very small κ , we can still use them to draw the boundary between the phases with soft and strong renormalization of the bending rigidity. That line can be formed with the values of critical coupling g_c beyond which the integral equation would lead to negative values of κ . This forbidden region corresponds in the renormalization group approach to the

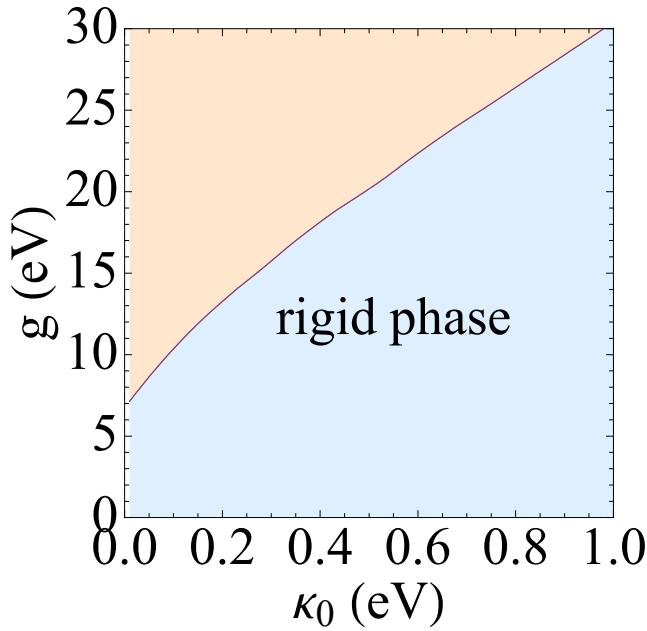


FIG. 3. Diagram showing the phases corresponding to a rigid long-distance regime of graphene (lower region) and pinning of the renormalized bending rigidity at very small values (upper region), in the space of nominal values of the rigidity κ_0 and deformation potential g . The value of $a^2 K_0$ was taken as 18 eV.

regime where the bending rigidity becomes trapped at very small values. The resulting phase diagram in the space of nominal values of the rigidity κ_0 and deformation potential g is shown in Fig. 3.

The phase with strong renormalization of the bending rigidity can be put in correspondence with the appearance of ripples in graphene, as very small values of κ imply a very large susceptibility for the development of a condensate (nonvanishing average value) of the flexural phonon field h . It is conceivable that the different degree of Coulomb screening may control which of the two phases is found in a real graphene sample, as the Coulomb interaction leads to a slight reduction in the charge susceptibility. Thus, graphene can be more prone to develop ripples or to buckle when surrounded by media with high dielectric constant, for which the values of $\chi(\mathbf{q}, 0)$ are maximized.

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